DC COMPONENTS CO., LTD.

RECTIFIER SPECIALISTS

MMB3505 THRU MMB3510

TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER

VOLTAGE RANGE - 50 to 1000 Volts *CURRENT - 35 Amperes*

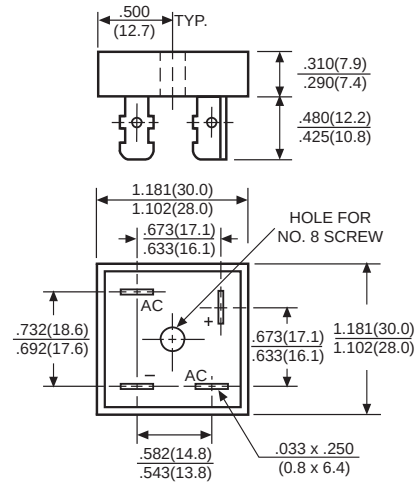
FEATURES

* Metal case for Maximum Heat Dissipation
* Diffused Junction
* High current capability
* Surge overload ratings - 400 Amperes
* Low forward voltage drop
* High Reliability

MECHANICAL DATA

* Case: Metal case, electrically isolated
* Epoxy: UL 94V-0 rate flame retardant
* Terminals: Plated .25"(6.35mm) Faston lugs, Solderable per MIL-STD-202E, Method 208 guaranteed
* Polarity: As marked
* Mounting position: Any
* Weight: 25 grams approx.

MMB-25



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

		SYMBOL	MMB3505	MMB351	MMB352	MMB354	MMB356	MMB358	MMB3510	UNITS
Maximum Recurrent Peak Reverse Voltage		V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage		V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Output Current at Tc = 55°C		I_O	35							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		I_{FSM}	400							Amps
Maximum Forward Voltage Drop per element at 17.5A DC		V_F	1.1							Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage per element	@TA = 25°C	I_R	10							µAmps
	@TA = 100°C		500							
I^2t Rating for Fusing (t<8.3ms)		I^2t	664							A^2Sec
Typical Junction Capacitance (Note1)		C_J	300							pF
Typical Thermal Resistance (Note 2)		RθJC	2.2							°C/W
Operating and Storage Temperature Range		T_J,T_{STG}	-55 to +150							°C

NOTES : 1.Measured at 1 MHz and applied reverse voltage of 4.0 volts.
2.Thermal Resistance from Junction to Case per leg.

Diode, Bridge Rectifiers INDEX ① | Diode, Bridge Rectifiers INDEX ② | Transistors, SCR, IC INDEX ① | Transistors, SCR, IC INDEX ② | EXIT

RATING AND CHARACTERISTIC CURVES (MMB3505 THRU MMB3510)

FIG. 1 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

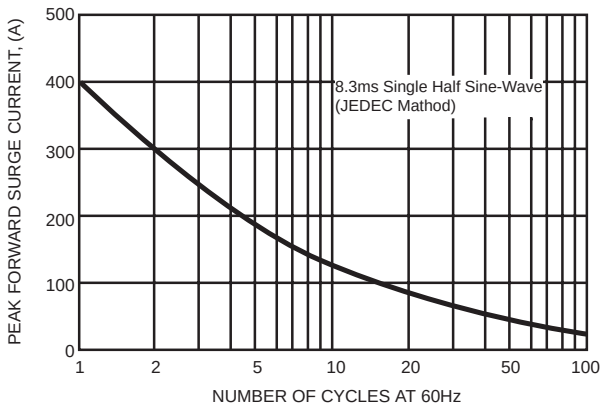


FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

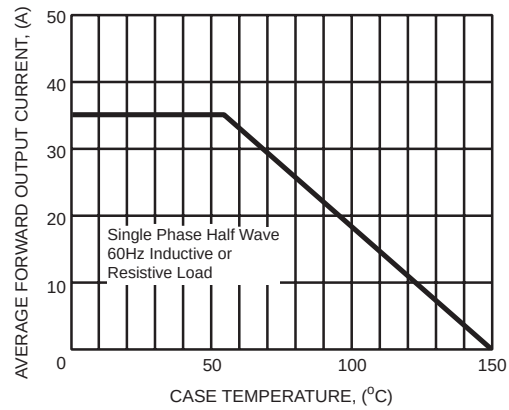


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

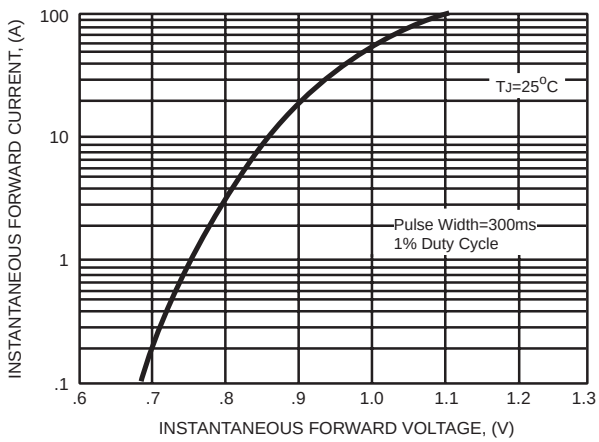
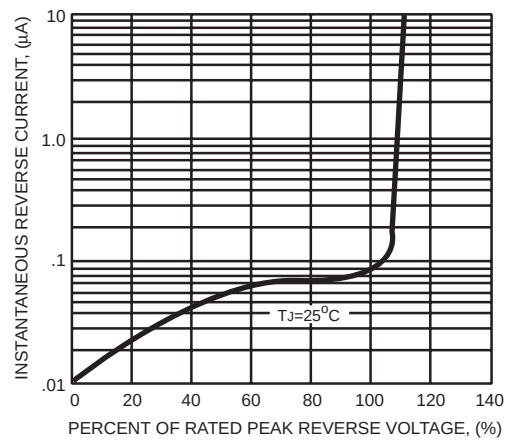


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS



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MMB3505W THRU MMB3510W

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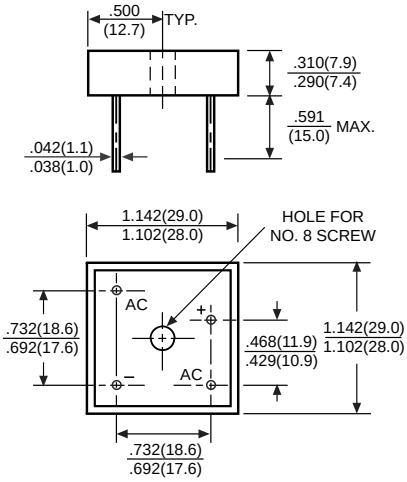
* Lead: MIL-STD-202E, Method 208 guaranteed
* Polarity: As marked
* Mounting position: Any
* Weight: 25 grams approx.

MMB-25W



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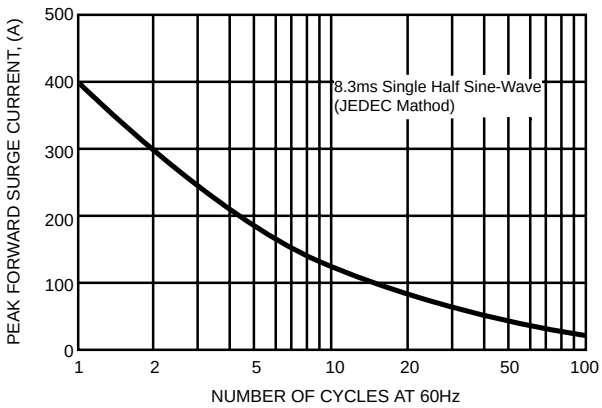

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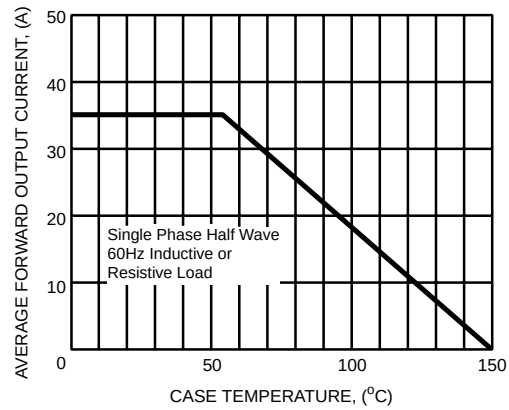

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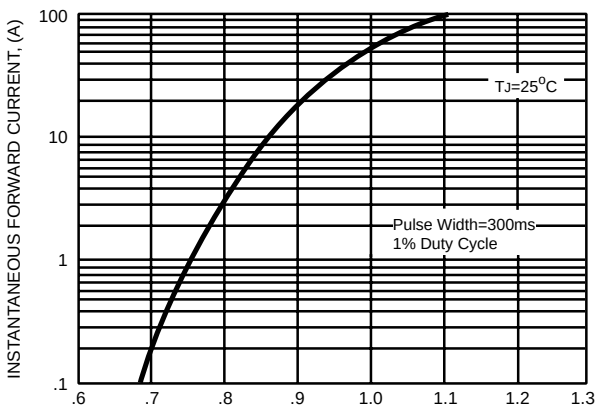

FIG. 4 - TYPICAL REVERSE CHARACTERISTICS